



## DUAL N-CHANNEL MATCHED MOSFET PAIR

### GENERAL DESCRIPTION

The ALD1101 is a monolithic dual N-channel matched transistor pair intended for a broad range of analog applications. These enhancement-mode transistors are manufactured with Advanced Linear Devices' enhanced AC MOS silicon gate CMOS process.

The ALD1101 offers high input impedance and negative current temperature coefficient. The transistor pair is matched for minimum offset voltage and differential thermal response, and it is designed for switching and amplifying applications in +2V to +12V systems where low input bias current, low input capacitance and fast switching speed are desired. Since these are MOSFET devices, they feature very large (almost infinite) current gain in a low frequency, or near DC, operating environment. When used with an ALD1102, a dual CMOS analog switch can be constructed. In addition, the ALD1101 is intended as a building block for differential amplifier input stages, transmission gates, and multiplexer applications.

The ALD1101 is suitable for use in precision applications which require very high current gain, beta, such as current mirrors and current sources. The high input impedance and the high DC current gain of the Field Effect Transistors result in extremely low current loss through the control gate. The DC current gain is limited by the gate input leakage current, which is specified at 50pA at room temperature. For example, DC beta of the device at a drain current of 5mA at 25°C is  $= 5\text{mA}/50\text{pA} = 100,000,000$ .

### FEATURES

- Low threshold voltage of 0.7V
- Low input capacitance
- Low Vos grades -- 2mV, 5mV, 10mV
- High input impedance --  $10^9\Omega$  typical
- Negative current ( $\beta$ s) temperature coefficient
- Enhancement-mode (normally off)
- DC current gain  $10^8$
- RoHS compliant

### ORDERING INFORMATION ("L" suffix denotes lead-free (RoHS))

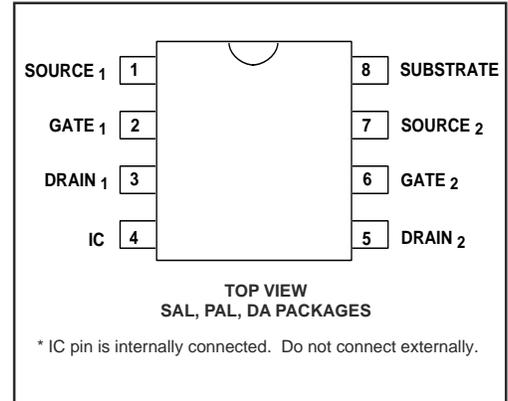
Operating Temperature Range		
0°C to +70°C	0°C to +70°C	-55°C to +125°C
8-Pin Small Outline Package (SOIC)	8-Pin Plastic Dip Package	8-Pin CERDIP Package
ALD1101ASAL	ALD1101APAL	
ALD1101BSAL	ALD1101BPAL	
ALD1101SAL	ALD1101PAL	ALD1101DA

\* Contact factory for leaded (non-RoHS) or high temperature versions.

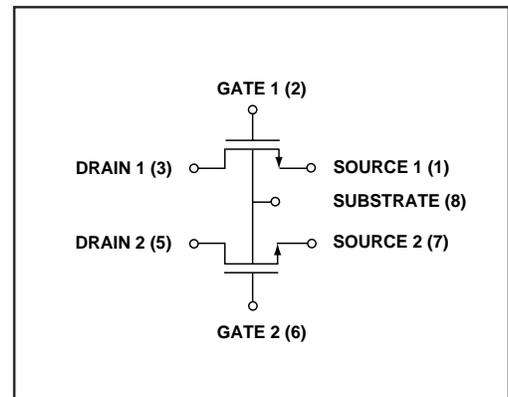
### APPLICATIONS

- Precision current mirrors
- Precision current sources
- Analog switches
- Choppers
- Differential amplifier input stage
- Voltage comparator
- Data converters
- Sample and Hold
- Analog inverter

### PIN CONFIGURATION



### BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Drain-source voltage, $V_{DS}$	_____	10.6V
Gate-source voltage, $V_{GS}$	_____	10.6V
Power dissipation	_____	500mW
Operating temperature range	SAL, PAL packages	0°C to +70°C
	DA package	-55°C to +125°C
Storage temperature range	_____	-65°C to +150°C
Lead temperature, 10 seconds	_____	+260°C

CAUTION: ESD Sensitive Device. Use static control procedures in ESD controlled environment.

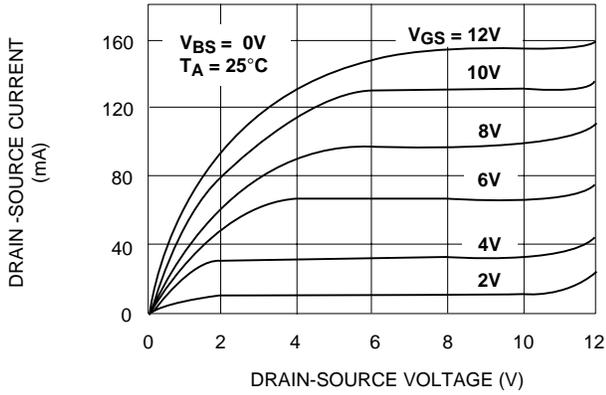
## OPERATING ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$  unless otherwise specified

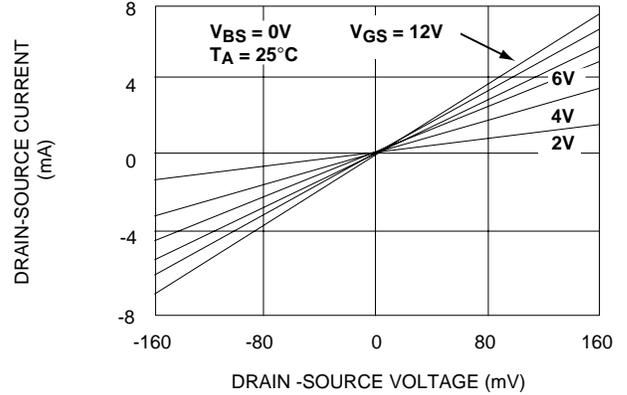
Parameter	Symbol	ALD 1101A			ALD1101B			ALD1101			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
Gate Threshold Voltage	$V_T$	0.4	0.7	1.0	0.4	0.7	1.0	0.4	0.7	1.0	V	$I_{DS} = 10\mu\text{A}$ $V_{GS} = V_{DS}$
Offset Voltage $V_{GS1} - V_{GS2}$	$V_{OS}$			2			5			10	mV	$I_{DS} = 100\mu\text{A}$ $V_{GS} = V_{DS}$
Gate Threshold Temperature Drift	$TC_{VT}$		-1.2			-1.2			-1.2		mV/°C	
On Drain Current	$I_{DS(ON)}$	25	40		25	40		25	40		mA	$V_{GS} = V_{DS} = 5V$
Transconductance	$G_{fs}$	5	10		5	10		5	10		mmho	$V_{DS} = 5V$ $I_{DS} = 10\text{mA}$
Mismatch	$\Delta G_{fs}$		0.5			0.5			0.5		%	
Output Conductance	$G_{OS}$		200			200			200		$\mu\text{mho}$	$V_{DS} = 5V$ $I_{DS} = 10\text{mA}$
Drain Source ON Resistance	$R_{DS(ON)}$		50	75		50	75		50	75	$\Omega$	$V_{DS} = 0.1V$ $V_{GS} = 5V$
Drain Source ON Resistance Mismatch	$\Delta R_{DS(ON)}$		0.5			0.5			0.5		%	$V_{DS} = 0.1V$ $V_{GS} = 5V$
Drain Source Breakdown Voltage	$BV_{DSS}$	12			12			12			V	$I_{DS} = 10\mu\text{A}$ $V_{GS} = 0V$
Off Drain Current	$I_{DS(OFF)}$		0.1	4 4		0.1	4 4		0.1	4 4	nA $\mu\text{A}$	$V_{DS} = 12V$ $V_{GS} = 0V$ $T_A = 125^\circ\text{C}$
Gate Leakage Current	$I_{GSS}$		1	50 10		1	50 10		1	50 10	pA nA	$V_{DS} = 0V$ $V_{GS} = 12V$ $T_A = 125^\circ\text{C}$
Input Capacitance	$C_{ISS}$		6	10		6	10		6	10	pF	

# TYPICAL PERFORMANCE CHARACTERISTICS

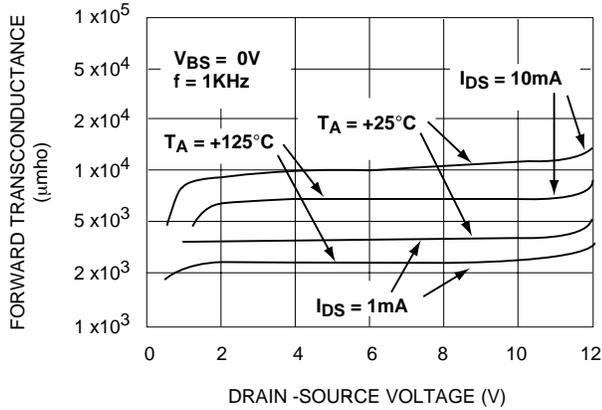
## OUTPUT CHARACTERISTICS



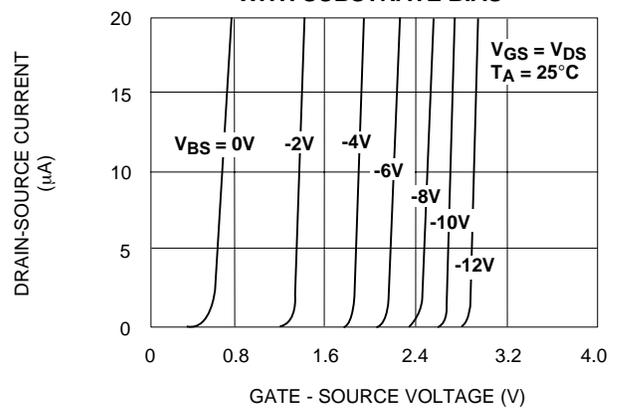
## LOW VOLTAGE OUTPUT CHARACTERISTICS



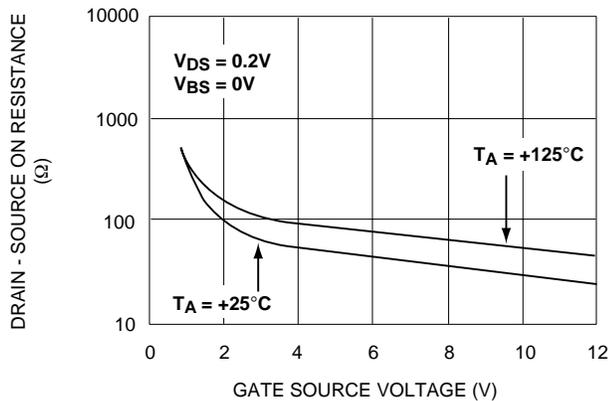
## FORWARD TRANSCONDUCTANCE vs. DRAIN-SOURCE VOLTAGE



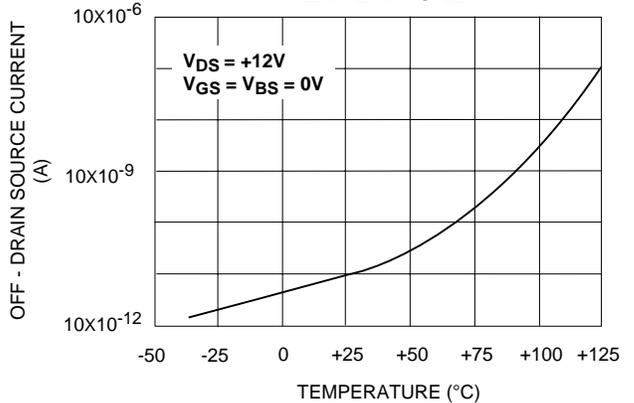
## TRANSFER CHARACTERISTIC WITH SUBSTRATE BIAS



## RDS (ON) vs. GATE - SOURCE VOLTAGE

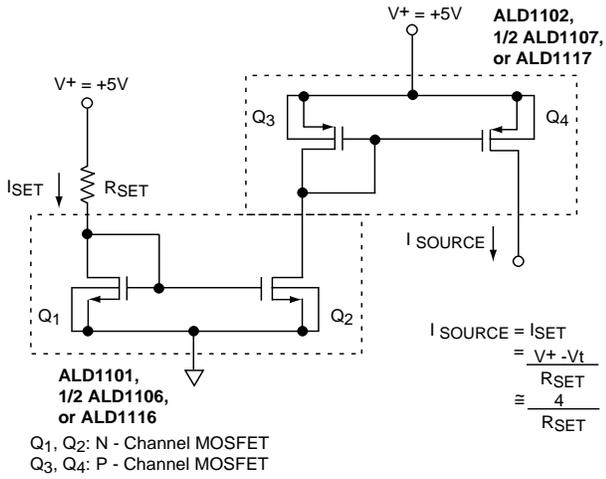


## OFF DRAIN - CURRENT vs. TEMPERATURE

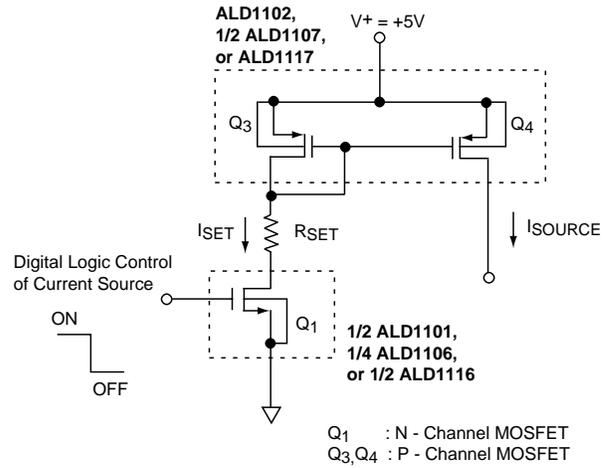


# TYPICAL APPLICATIONS

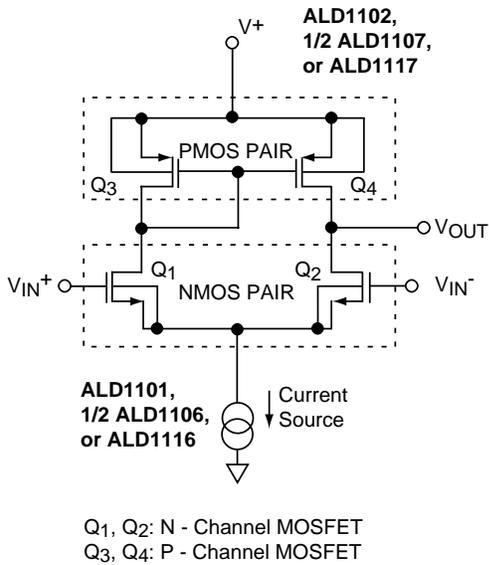
## CURRENT SOURCE MIRROR



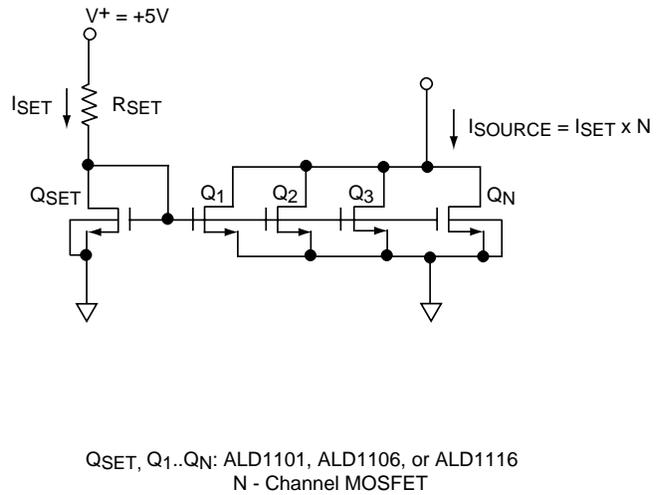
## CURRENT SOURCE WITH GATE CONTROL



## DIFFERENTIAL AMPLIFIER



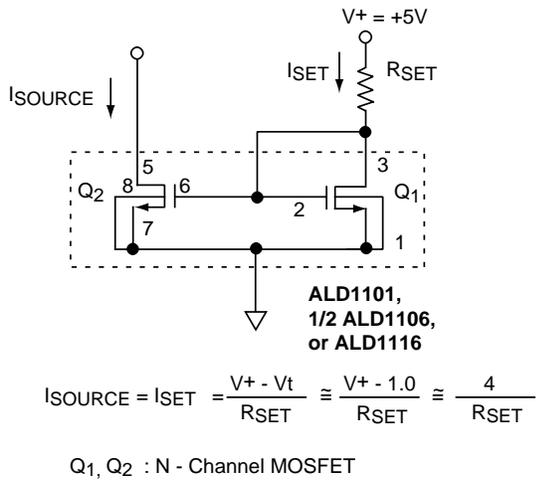
## CURRENT SOURCE MULTIPLICATION



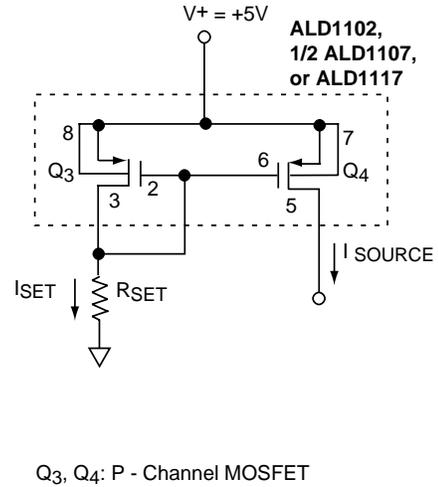
## TYPICAL APPLICATIONS (cont.)

### BASIC CURRENT SOURCES

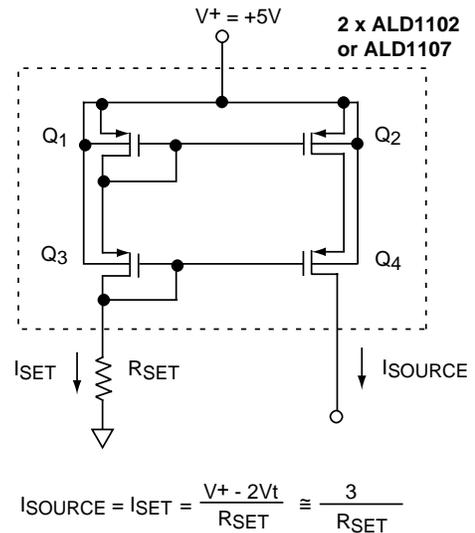
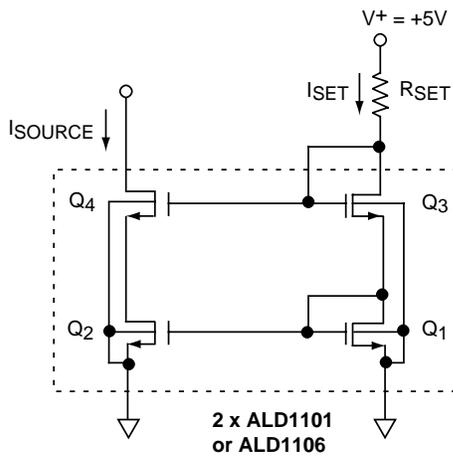
#### N- CHANNEL CURRENT SOURCE



#### P- CHANNEL CURRENT SOURCE

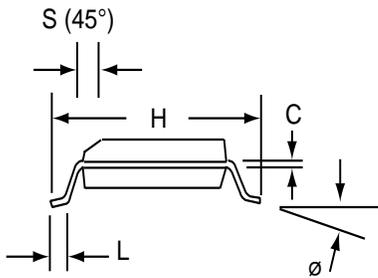
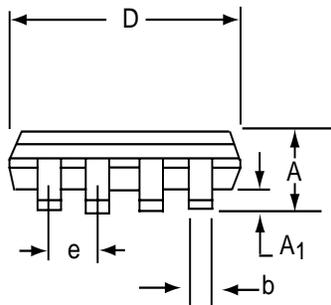
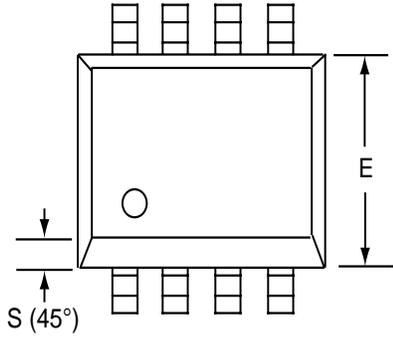


### CASCODE CURRENT SOURCES



# SOIC-8 PACKAGE DRAWING

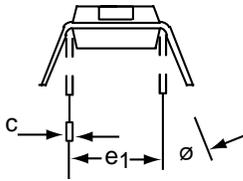
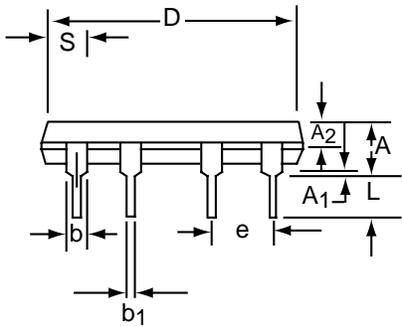
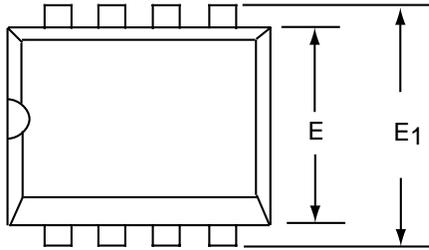
## 8 Pin Plastic SOIC Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.25	0.004	0.010
b	0.35	0.45	0.014	0.018
C	0.18	0.25	0.007	0.010
D-8	4.69	5.00	0.185	0.196
E	3.50	4.05	0.140	0.160
e	1.27 BSC		0.050 BSC	
H	5.70	6.30	0.224	0.248
L	0.60	0.937	0.024	0.037
Ø	0°	8°	0°	8°
S	0.25	0.50	0.010	0.020

# PDIP-8 PACKAGE DRAWING

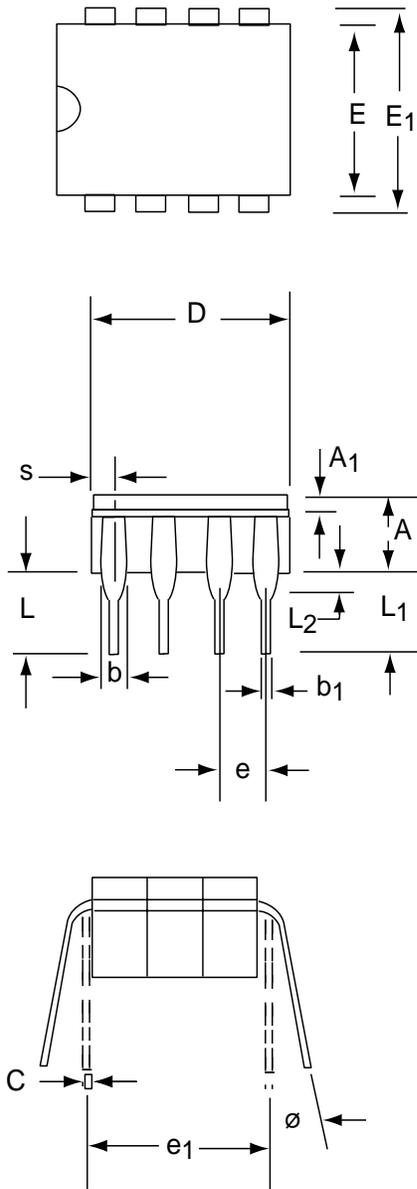
## 8 Pin Plastic DIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.81	5.08	0.105	0.200
A <sub>1</sub>	0.38	1.27	0.015	0.050
A <sub>2</sub>	1.27	2.03	0.050	0.080
b	0.89	1.65	0.035	0.065
b <sub>1</sub>	0.38	0.51	0.015	0.020
c	0.20	0.30	0.008	0.012
D-8	9.40	11.68	0.370	0.460
E	5.59	7.11	0.220	0.280
E <sub>1</sub>	7.62	8.26	0.300	0.325
e	2.29	2.79	0.090	0.110
e <sub>1</sub>	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
S-8	1.02	2.03	0.040	0.080
∅	0°	15°	0°	15°

# CERDIP-8 PACKAGE DRAWING

## 8 Pin CERDIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.55	5.08	0.140	0.200
A <sub>1</sub>	1.27	2.16	0.050	0.085
b	0.97	1.65	0.038	0.065
b <sub>1</sub>	0.36	0.58	0.014	0.023
C	0.20	0.38	0.008	0.015
D-8	--	10.29	--	0.405
E	5.59	7.87	0.220	0.310
E <sub>1</sub>	7.73	8.26	0.290	0.325
e	2.54 BSC		0.100 BSC	
e <sub>1</sub>	7.62 BSC		0.300 BSC	
L	3.81	5.08	0.150	0.200
L <sub>1</sub>	3.18	--	0.125	--
L <sub>2</sub>	0.38	1.78	0.015	0.070
S	--	2.49	--	0.098
∅	0°	15°	0°	15°